# RENESAS

# HD74LV2GT86A

2-input Exclusive-OR Gate / CMOS Logic Level Shifter

REJ03D0147-0200Z (Previous ADE-205-669A (Z)) Rev.2.00 Oct.20.2003

### Description

The HD74LV2GT86A performs the Boolean functions  $Y = A \oplus B$  or  $Y = \overline{AB} + A\overline{B}$  in positive logic. A common application is as a true / complement element. If one of the inputs is low, the other input will be reproduced in true form at the output. If one of the inputs is high, the signal on the other input will be reproduced inverted form at the output. The input protection circuitry on this device allows over voltage tolerance on the input, allowing the device to be used as a logic–level translator from 3.0 V CMOS Logic to 5.0 V CMOS Logic or from 1.8 V CMOS logic to 3.0 V CMOS Logic while operating at the high-voltage power supply. Low voltage and high-speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

### Features

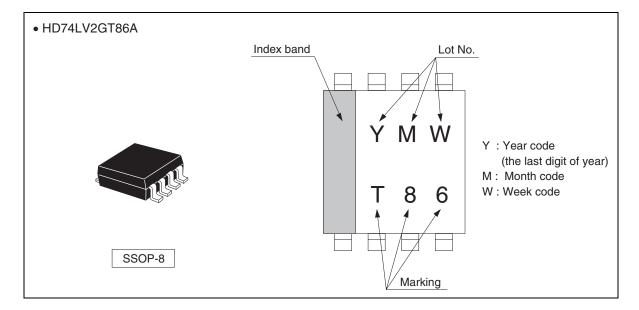
- The basic gate function is lined up as Renesas uni logic series.
- Supplied on emboss taping for high-speed automatic mounting.
- TTL compatible input level. Supply voltage range : 3.0 to 5.5 V Operating temperature range : -40 to +85°C
- Logic-level translate function
   3.0 V CMOS logic → 5.0 V CMOS logic (@V<sub>CC</sub> = 5.0 V)
   1.8 V or 2.5 V CMOS logic → 3.3 V CMOS logic (@V<sub>CC</sub> = 3.3 V)
- All inputs  $V_{IH}$  (Max.) = 5.5 V (@V<sub>CC</sub> = 0 V to 5.5 V) All outputs  $V_0$  (Max.) = 5.5 V (@V<sub>CC</sub> = 0 V)
- Output current  $\pm 6 \text{ mA}$  (@V<sub>CC</sub> = 3.0 V to 3.6 V),  $\pm 12 \text{ mA}$  (@V<sub>CC</sub> = 4.5 V to 5.5 V)
- All the logical input has hysteresis voltage for the slow transition.
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LV2GT86AUSE	SSOP-8 pin	TTP-8DBV	US	E (3,000 pcs/reel)

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### **Outline and Article Indication**



### **Function Table**

#### Inputs

Α		3	Output Y
L	l	-	L
L	I	4	Н
Н	l	-	Н
Н	I	4	L
Ц·	High level		

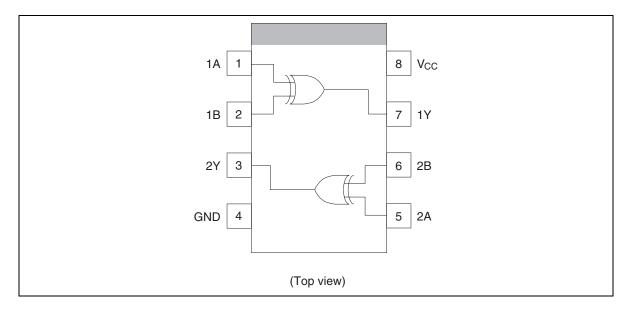
H: High level

L: Low level

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### **Pin Arrangement**



## **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage	V <sub>CC</sub>	–0.5 to 7.0	V	
Input voltage	V <sub>IN</sub>	–0.5 to 7.0	V	
Output voltage	V <sub>OUT</sub>	–0.5 to V <sub>CC</sub> +0.5	V	Output : H or L
		-0.5 to 7.0		V <sub>CC</sub> : OFF
Input diode current	I <sub>IK</sub>	-20	mA	
Output diode current	I <sub>OK</sub>	±50	mA	
output current	I <sub>OUT</sub>	±25	mA	
V <sub>CC</sub> , GND current	I <sub>CC</sub> or I <sub>GND</sub>	±50	mA	
power dissipation	P <sub>T</sub>	200	mW	
Storage temperature	Tstg	-65 to 150	°C	

### **Recommended Operating Conditions**

Item	Symbol	Ratings	Unit
Supply voltage	V <sub>CC</sub>	3.0 to 5.5	V
Input voltage	V <sub>IN</sub>	0 to 5.5	V
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	-40 to +85	°C
Input rise / fall time	t <sub>r</sub> , t <sub>f</sub>	0 to 100 ( $V_{CC}$ = 3.0 to 3.6 V)	ns
		0 to 20 (V <sub>CC</sub> = 4.5 to 5.5 V)	

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#### **Electrical Characteristic**

#### • Ta = -40 to $85^{\circ}C$

Item	Symbol	V <sub>cc</sub> (V) *	Min	Тур	Мах	Unit	Test condition
Input voltage	VIH	3.0 to 3.6	1.5	_	—	V	
		4.5 to 5.5	2.0	_	—	_	
	V <sub>IL</sub>	3.0 to 3.6	_	_	0.6		
		4.5 to 5.5		_	0.8	_	
Hysteresis voltage	V <sub>H</sub>	3.3	_	0.10	—	V	$V_T^+ - V_T^-$
		5.0	_	0.15	_		
Output voltage	V <sub>OH</sub>	Min to Max	V <sub>CC</sub> -0.1	_	_	V	I <sub>OH</sub> = -50 μA
		3.0	2.48	_	—	_	$I_{OH} = -6 \text{ mA}$
		4.5	3.8	_	_		I <sub>OH</sub> = -12 mA
	Vol	Min to Max		_	0.1	_	I <sub>OL</sub> = 50 μA
		3.0	_	_	0.44		$I_{OL} = 6 \text{ mA}$
		4.5	_	_	0.55		I <sub>OL</sub> = 12 mA
Input current	I <sub>IN</sub>	0 to 5.5	_	_	±1	μΑ	$V_{IN} = 5.5 \text{ V or GND}$
Quiescent supply current	I <sub>CC</sub>	5.5	—	—	10	μA	$V_{IN} = V_{CC}$ or GND, $I_0 = 0$
	$\Delta I_{CC}$	5.5	_	_	1.5	mA	One input $V_{IN} = 3.4 V$ , other input $V_{CC}$ or GND
Output leakage current	I <sub>OFF</sub>	0	—	—	5	μΑ	V <sub>O</sub> = 5.5 V
Input capacitance	C <sub>IN</sub>	5.0	_	2.5	—	pF	$V_{IN} = V_{CC} \text{ or } GND$

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

### **Switching Characteristics**

<sup>•</sup>  $V_{CC} = 3.3 \pm 0.3 V$ 

		Ta = 2	25°C		Ta =	40 to 85°C		Test	FROM	то
ltem	Symbol	Min	Тур	Max	Min	Max	Unit	Conditions	(Input)	(Output)
Propagation	t <sub>PLH</sub>	_	8.0	12.5	1.0	14.0	ns	$C_L = 15 \text{ pF}$	A or B	Y
delay time	t <sub>PHL</sub>	_	9.5	17.0	1.0	19.0	_	$C_L = 50 \text{ pF}$	_	

#### • $V_{CC} = 5.0 \pm 0.5 \text{ V}$

		Ta = 2	25°C		Ta = -40 to 85°C			Test	FROM	то
ltem	Symbol	Min	Тур	Max	Min	Max	Unit	Conditions	(Input)	(Output)
Propagation	t <sub>PLH</sub>	_	5.5	7.5	1.0	8.5	ns	$C_L = 15 \text{ pF}$	A or B	Y
delay time	t <sub>PHL</sub>	—	6.5	10.3	1.0	11.5	-	$C_L = 50 \text{ pF}$	_	

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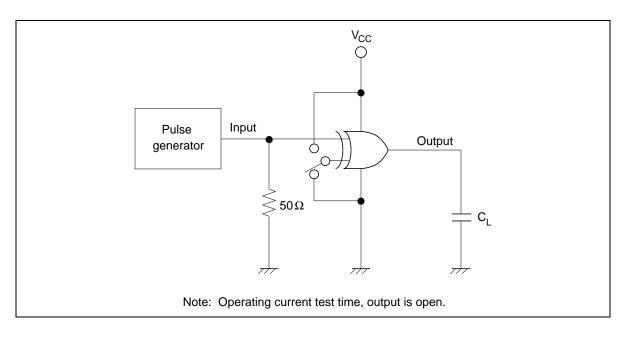
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### **Operating Characteristics**

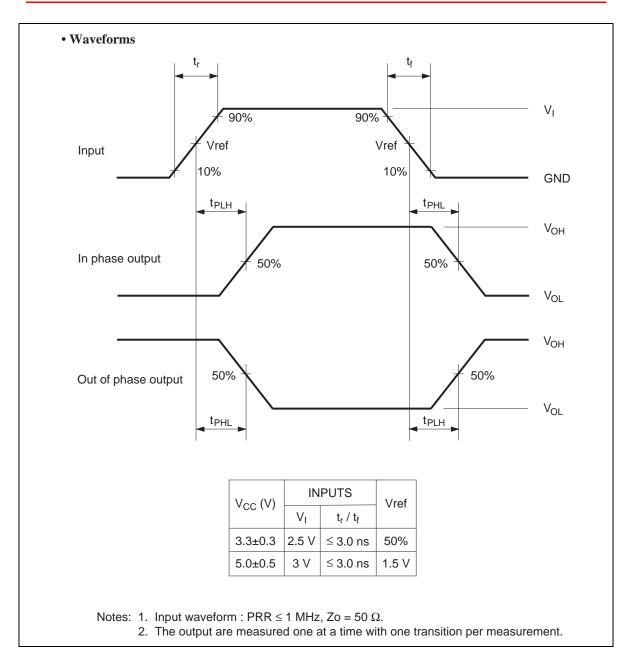
•  $C_L = 50 \text{ pF}$ 

			Ta = 2	5°C			
Item	Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Unit	Test Conditions
Power dissipation capacitance	$C_{\text{PD}}$	5.0	_	11.0	_	pF	f = 10 MHz

## **Test Circuit**

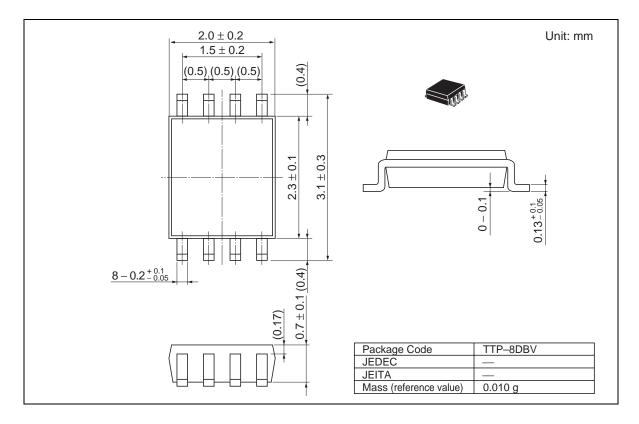






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### **Package Dimensions**



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